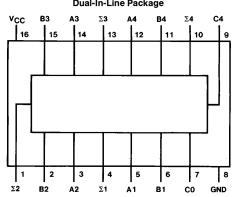
Connection Diagram



Order Number 54LS283DMQB, 54LS283FMQB, 54LS283LMQB, DM54LS283J, DM54LS283W, DM74LS283M or DM74LS283N See NS Package Number E20A, J16A, M16A, N16E or W16A

TL/F/6421-1

Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage 7V 7V Input Voltage Operating Free Air Temperature Range

DM54LS and 54LS -55°C to +125°C DM74LS 0°C to +70°C -65°C to +150°C Storage Temperature Range

table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics"

Recommended Operating Conditions

Symbol	Parameter	DM54LS283			DM74LS283			Units
	i drameter	Min	Nom	Max	Min	Nom	Max	Omis
V _{CC}	Supply Voltage	4.5	5	5.5	4.75	5	5.25	V
V_{IH}	High Level Input Voltage	2			2			V
V _{IL}	Low Level Input Voltage			0.7			0.8	V
Гон	High Level Output Current			-0.4			-0.4	mA
l _{OL}	Low Level Output Current			4			8	mA
T _A	Free Air Operating Temperature	-55		125	0		70	°C

Electrical Characteristics over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ (Note 1)	Max	Units	
VI	Input Clamp Voltage	$V_{CC} = Min, I_I = -18 \text{ mA}$			-1.5	V	
V _{OH}	High Level Output	V _{CC} = Min, I _{OH} = Max	DM54	2.5	3.4		V
	Voltage	$V_{IL} = Max, V_{IH} = Min$	DM74	2.7	3.4		
V _{OL}	Low Level Output Voltage	$V_{CC} = Min, I_{OL} = Max$	DM54		0.25	0.4	V
		$V_{IL} = Max, V_{IH} = Min$	DM74		0.35	0.5	
		$I_{OL} = 4 \text{ mA}, V_{CC} = Min$	DM74		0.25	0.4	
lį	Input Current @ Max Input Voltage	$V_{CC} = Max$ $V_{I} = 7V$	A, B			0.2	- mA
			C0			0.1	
I _{IH}	High Level Input	$V_{CC} = Max$ $V_I = 2.7V$	A, B			40	- μΑ
	Current		C0			20	
I _{IL}	Low Level Input	V _{CC} = Max	A, B			-0.8	- mA
	Current	$V_{I} = 0.4V$	C0			-0.4	
los	Short Circuit	V _{CC} = Max	DM54	-20		-100	- mA
	Output Current	(Note 2)	DM74	-20		-100	
I _{CC1}	Supply Current	V _{CC} = Max (Note 3)			19	34	mA
I _{CC2}	Supply Current	V _{CC} = Max (Note 4)			22	39	mA

Note 1: All typicals are at $V_{CC} = 5V$, $T_A = 25^{\circ}C$.

Note 2: Not more than one output should be shorted at a time, and the duration should not exceed one second.

Note 3: I_{CC1} is measured with all outputs open, all B inputs low and all other inputs at 4.5V, or all inputs at 4.5V.

Note 4: I_{CC2} is measured with all outputs open and all inputs grounded.

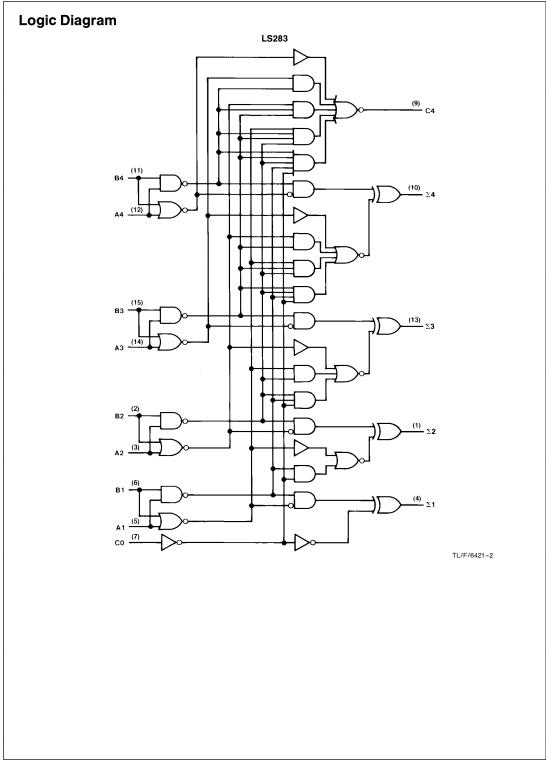
Switching Characteristics at V _{CC} =	5V and $T_A = 25^{\circ}$ C (See Section 1 for Test Waveforms and Output Load)
--	--

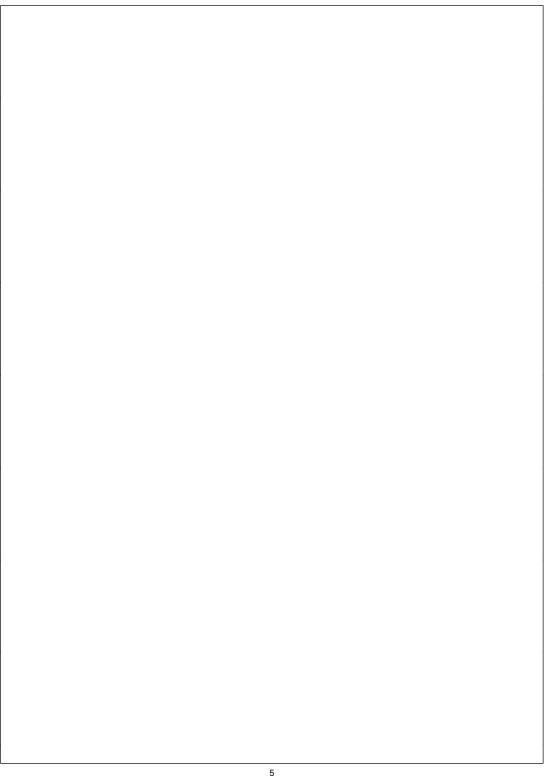
		From (Input) To (Output)						
Symbol	Parameter		C _L = 15 pF		C _L = 50 pF		Units	
		To (Output)	Min	n Max Min Max		Max		
t _{PLH}	Propagation Delay Time Low to High Level Output	C0 to Σ1, Σ2		24		28	ns	
t _{PHL}	Propagation Delay Time High to Low Level Output	C0 to Σ1, Σ2		24		30	ns	
t _{PLH}	Propagation Delay Time Low to High Level Output	C0 to Σ3		24		28	ns	
t _{PHL}	Propagation Delay Time High to Low Level Output	C0 to Σ3		24		30	ns	
t _{PLH}	Propagation Delay Time Low to High Level Output	C0 to Σ4		24		28	ns	
t _{PHL}	Propagation Delay Time High to Low Level Output	C0 to Σ4		24		30	ns	
t _{PLH}	Propagation Delay Time Low to High Level Output	A_i or B_i to Σ_i		24		28	ns	
t _{PHL}	Propagation Delay Time High to Low Level Output	A_i or B_i to Σ_i		24		30	ns	
t _{PLH}	Propagation Delay Time Low to High Level Output	C0 to C4		17		24	ns	
t _{PHL}	Propagation Delay Time High to Low Level Output	C0 to C4		17		25	ns	
t _{PLH}	Propagation Delay Time Low to High Level Output	A _i or B _i to C4		17		24	ns	
t _{PHL}	Propagation Delay Time High to Low Level Output	A _i or B _i to C4		17		26	ns	

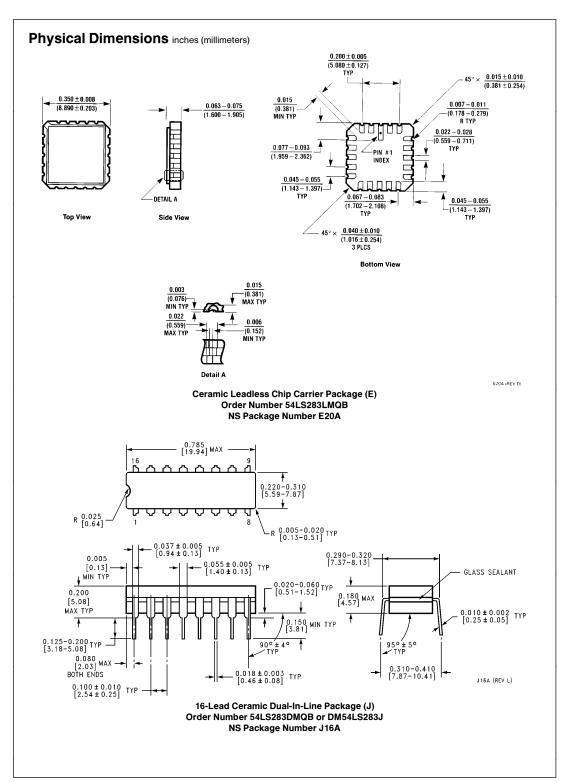
Function Table

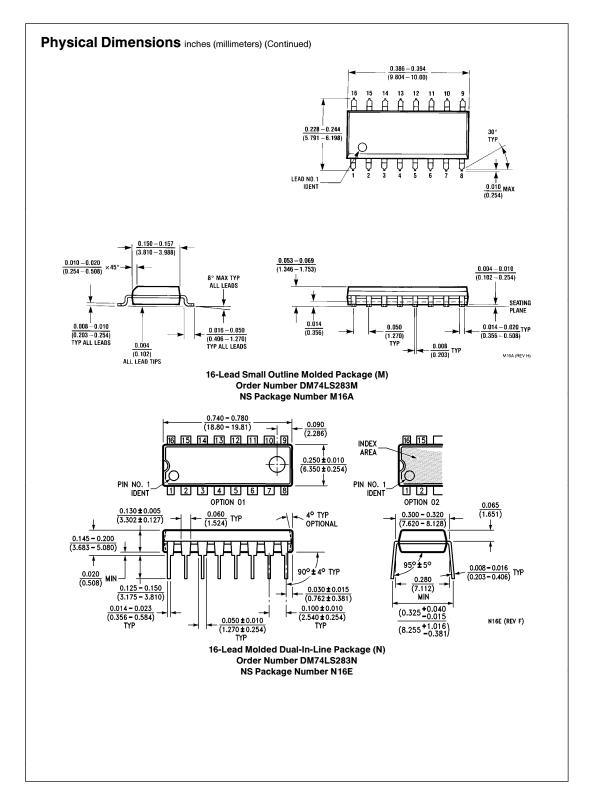
				Outputs						
Input				When C0 = L			When C0 = H			
			When C2 = L			When C2 = H				
A1 /	B1 /	A2 /	B2 /	Σ1	Σ2	C2 /	Σ1	Σ2	C2	
A3	B3	A4	B4	Σ3	Σ4	C4	Σ3	Σ4	C4	
L	L	L	L	L	L	Ĺ	Н	L	L	
Н	L	L	L	Н	L	L	L	Н	L	
L	н	L	L	Н	L	L	L	Н	L	
Н	ј н	L	L	L	н	L	Н	Н	L	
L	L	н	L	L	Н	L	Н	Н	L	
н	L	H	L	Н	Н	L	L	L	Н	
L	Н	н	L	н	н	L	L	L	н	
Н	н	Н	L	L	L	Н	н	L	Н	
L	L	L	н	L	Н	L	Н	Н	L	
н	L	L	Н	Н	н	L	L	L	н	
L	Н	L	н	Н	Н	L	L	L	н	
Н	Н	L	н	L	L	н	Н	L	н	
L	L	Н	Н	L	L	н	н	L	Н	
н	L	н	н	Н	L	н	L	Н	Н	
L	Н	Н	н	н	L	н	L	н	Н	
н	Н	Н	Н	L	Н	н	Н	Н	Н	

H = High Level, L = Low Level **Note:** Input conditions at A1, B1, A2, B2, and C0 are used to determine outputs Σ 1 and Σ 2 and the value of the internal carry C2. The values at C2, A3, B3, A4, and B4 are then used to determine outputs Σ 3, Σ 4, and C4.

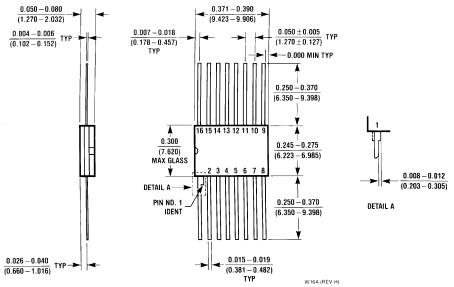








Physical Dimensions inches (millimeters) (Continued)



16-Lead Ceramic Flat Package (W) Order Number 54LS283FMQB or DM54LS283W NS Package Number W16A

LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform, when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



National Semiconductor Corporation 1111 West Bardin Road Arlington, TX 76017 Tel: 1(800) 272-9959 Fax: 1(800) 737-7018

___ National Semiconductor Europe

Europe Fax: (+49) 0-180-530 85 86 Email: cnjwge@tevm2.nsc.com
Deutsch Tel: (+49) 0-180-530 85 85 English Tel: (+49) 0-180-532 78 32 Français Tel: (+49) 0-180-532 93 88 Italiano Tel: (+49) 0-180-532 16 80

National Semiconductor Hong Kong Ltd. 13th Floor, Straight Block, Ocean Centre, 5 Canton Rd. Tsimshatsui, Kowloon Hong Kong Tel: (852) 2737-1600 Fax: (852) 2736-9960

National Semiconductor Japan Ltd. Tel: 81-043-299-2309 Fax: 81-043-299-2408